

1SS380

Diodes

Switching diode

1SS380

● **Applications**

Low leakage switching

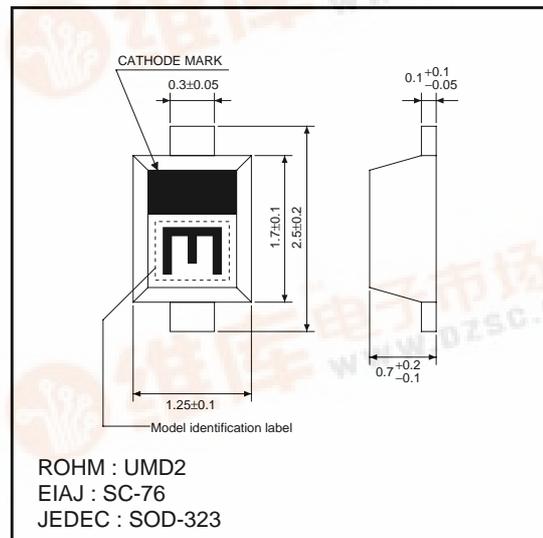
● **Features**

- 1) Small surface mounting type. (UMD2)
- 2) Ultra low I_R. (I_R=40pA Typ.)
- 3) High reliability.

● **Construction**

Silicon epitaxial planar

● **External dimensions (Units : mm)**



● **Absolute maximum ratings (Ta = 25°C)**

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V _{RM}	40	V
DC reverse voltage	V _R	35	V
Peak forward current	I _{FM}	225	mA
Mean rectifying current	I _o	100	mA
Surge current (1s)	I _{surge}	400	mA
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	-55~+125	°C

● **Electrical characteristics (Ta = 25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _F	-	-	1.2	V	I _F =100mA
Reverse current	I _R	-	-	10	nA	V _R =20V
Capacitance between terminals	C _T	-	-	5.0	pF	V _R =0.5V, f=1MHz

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● Electrical characteristic curves (Ta = 25°C)

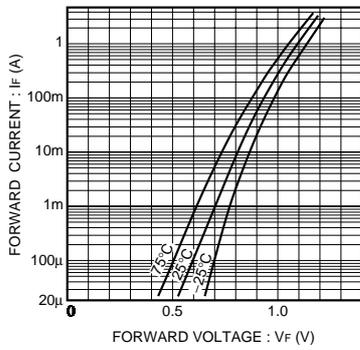


Fig. 1 Forward characteristics

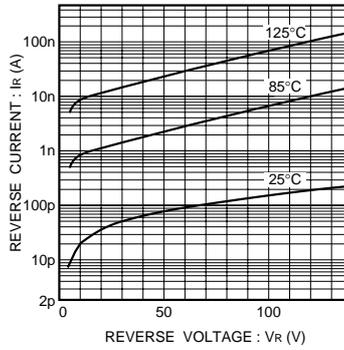


Fig. 2 Reverse characteristics

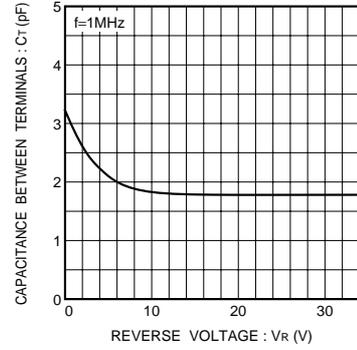


Fig. 3 Capacitance between terminals characteristics

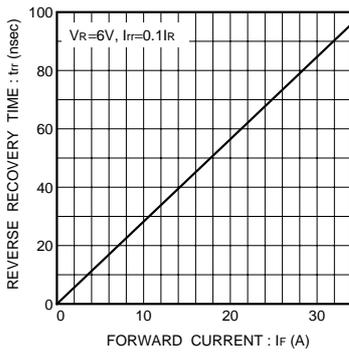


Fig. 4 Reverse recovery time characteristics

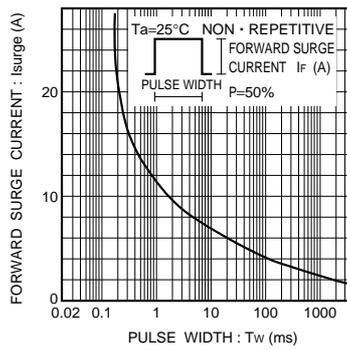


Fig. 5 Surge current characteristics

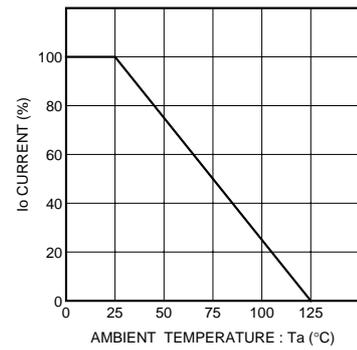


Fig. 6 Derating curve (mounting on glass epoxy PCBs)